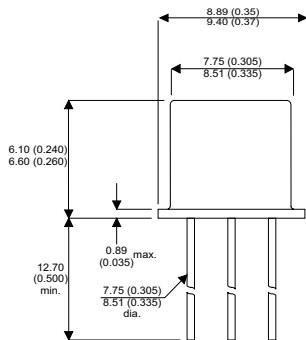


**MECHANICAL DATA**

Dimensions in mm (inches)

**MEDIUM POWER SILICON  
NPN PLANAR TRANSISTOR**

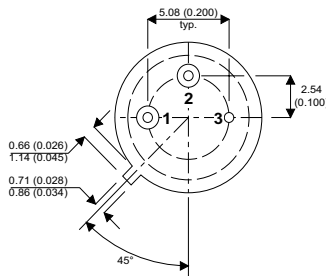


General purpose NPN Transistor  
in a hermetic TO39 package.

**$V_{CEO} = 100V$**

**$I_C = 1A$**

**$P_T = 5W$**



**TO39 PACKAGE**

**Underside View**

Pin 1 = Emitter    Pin 2 = Base    Pin 3 = Collector

**ABSOLUTE MAXIMUM RATINGS** ( $T_{case} = 25^{\circ}C$  unless otherwise stated)

$V_{CBO}$	Collector – Base Voltage	120V
$V_{CEO}$	Collector – Emitter Voltage	100V
$V_{EBO}$	Emitter – Base Voltage	6V
$V_{CER}$	Collector – Emitter Sustaining Voltage	100V
$I_C$	Collector Current	1A
$P_{TOT}$	Dissipation @ $T_{amb} = 25^{\circ}C$	1W
	@ Case Temp. = $100^{\circ}C$	2.9W
	@ Case Temp. = $25^{\circ}C$	5W
	Derating linearly	$175^{\circ}C$
$T_{stg}, T_j$	Storage and Operating Junction Temperature	$-65$ to $175^{\circ}C$

**ELECTRICAL CHARACTERISTICS** ( $T_{\text{case}} = 25^{\circ}\text{C}$  unless otherwise stated)

Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$V_{\text{CEO(SUS)}}$ Collector – Emitter Sustaining Voltage	$I_{\text{C}} = 10\text{mA}$ $I_{\text{B}} = 0$	100			
$V_{\text{CE(sat)}}$ Collector – Emitter Saturation Voltage	$I_{\text{C}} = 200\text{mA}$ $I_{\text{B}} = 20\text{mA}$			1.2	V
$V_{\text{BE(sat)}}$ Base – Emitter Saturation Voltage	$I_{\text{C}} = 200\text{mA}$ $I_{\text{B}} = 20\text{mA}$			1.5	
$I_{\text{CBO}}$ Collector Cut-off Current	$V_{\text{CB}} = V_{\text{CE}}$ $I_{\text{E}} = 0$ $T_{\text{amb}} = 100^{\circ}\text{C}$			1	V
				60	
$I_{\text{EBO}}$ Emitter - Base Reverse Current	$V_{\text{EB}} = 5\text{V}$ $I_{\text{C}} = 0$			0.1	
$h_{\text{FE}}$ DC Current Gain	$V_{\text{CE}} = 10\text{V}$ $I_{\text{C}} = 10\text{mA}$	30			—
	$V_{\text{CE}} = 10\text{V}$ $I_{\text{C}} = 200\text{mA}$	40		120	
$f_{\text{T}}$ Gain Bandwidth Product	$V_{\text{CE}} = 10\text{V}$ $I_{\text{C}} = 50\text{mA}$ $f = 10\text{MHz}$	60	250		MHz
NF Noise Figure	$V_{\text{CE}} = 10\text{V}$ $I_{\text{C}} = 300\mu\text{A}$ $f = 1\text{KHz}$		6		dB
$C_{\text{ob}}$ Output Capacitance	$V_{\text{CB}} = 10\text{V}$ $f = 0$			25	pF
$C_{\text{ib}}$ Input Capacitance	$V_{\text{EB}} = 1\text{V}$ $f = 0$			100	